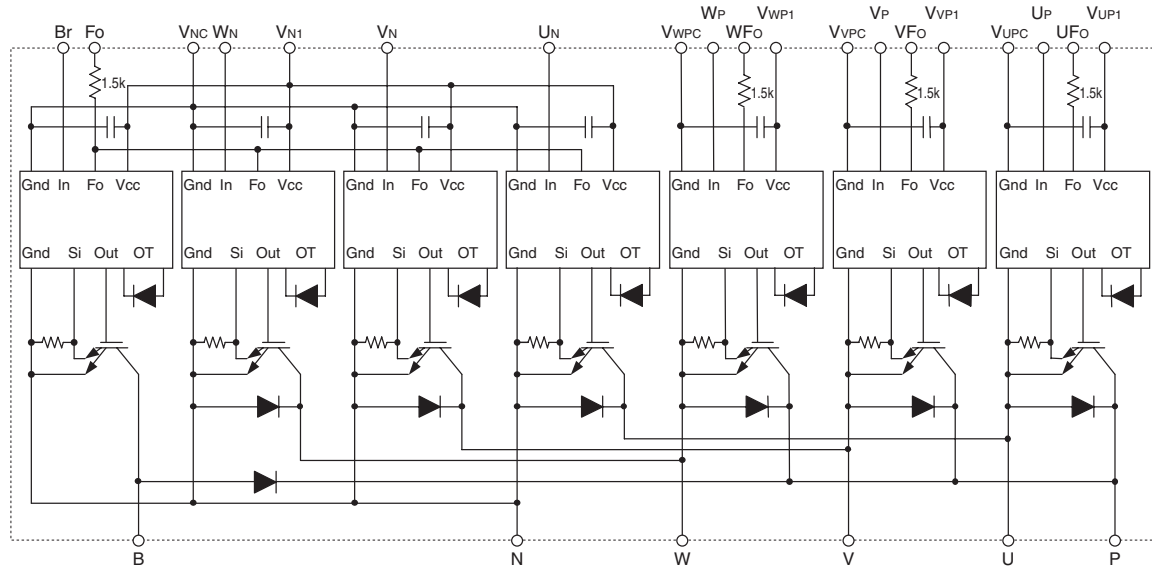


PM200RL1A060**FLAT-BASE TYPE
INSULATED PACKAGE****INTERNAL FUNCTIONS BLOCK DIAGRAM****MAXIMUM RATINGS** ($T_j = 25^\circ\text{C}$, unless otherwise noted)**INVERTER PART**

Symbol	Parameter	Condition	Ratings	Unit
V_{CES}	Collector-Emitter Voltage	$V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$	600	V
$\pm I_C$	Collector Current	$T_c = 25^\circ\text{C}$ (Note-1)	200	A
$\pm I_{CP}$	Collector Current (Peak)	$T_c = 25^\circ\text{C}$	400	A
P_C	Collector Dissipation	$T_c = 25^\circ\text{C}$ (Note-1)	625	W
T_j	Junction Temperature		$-20 \sim +150$	$^\circ\text{C}$

*: T_c measurement point is just under the chip.**BRAKE PART**

Symbol	Parameter	Condition	Ratings	Unit
V_{CES}	Collector-Emitter Voltage	$V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$	600	V
I_C	Collector Current	$T_c = 25^\circ\text{C}$ (Note-1)	100	A
I_{CP}	Collector Current (Peak)	$T_c = 25^\circ\text{C}$	200	A
P_C	Collector Dissipation	$T_c = 25^\circ\text{C}$ (Note-1)	390	W
I_F	FWDi Forward Current	$T_c = 25^\circ\text{C}$	100	A
$V_{R(DC)}$	FWDi Rated DC Reverse Voltage	$T_c = 25^\circ\text{C}$	600	V
T_j	Junction Temperature		$-20 \sim +150$	$^\circ\text{C}$

CONTROL PART

Symbol	Parameter	Condition	Ratings	Unit
V_D	Supply Voltage	Applied between : $V_{UP1}-V_{UPC}$, $V_{VP1}-V_{VPC}$ $V_{WP1}-V_{WPC}$, $V_{N1}-V_{NC}$	20	V
V_{CIN}	Input Voltage	Applied between : U_P-V_{UPC} , V_P-V_{VPC} , W_P-V_{WPC} $U_N \cdot V_N \cdot W_N \cdot B_r-V_{NC}$	20	V
V_{FO}	Fault Output Supply Voltage	Applied between : $U_{FO}-V_{UPC}$, $V_{FO}-V_{VPC}$, $W_{FO}-V_{WPC}$ F_O-V_{NC}	20	V
I_{FO}	Fault Output Current	Sink current at U_{FO} , V_{FO} , W_{FO} , F_O terminals	20	mA

PM200RL1A060**FLAT-BASE TYPE
INSULATED PACKAGE****TOTAL SYSTEM**

Symbol	Parameter	Condition	Ratings	Unit
V _{CC(prot)}	Supply Voltage Protected by SC	V _D = 13.5 ~ 16.5V Inverter Part, T _j = +125°C Start	400	V
V _{CC(surge)}	Supply Voltage (Surge)	Applied between : P-N, Surge value	500	V
T _{stg}	Storage Temperature		-40 ~ +125	°C
V _{iso}	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base, AC 1 min.	2500	V _{rms}

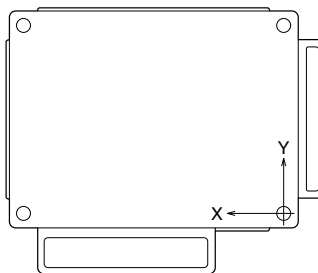
THERMAL RESISTANCES

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
R _{th(j-c)Q}	Junction to case Thermal Resistances	Inverter IGBT part (per 1 element) (Note-1)	—	—	0.20	°C/W
R _{th(j-c)F}		Inverter FWDi part (per 1 element) (Note-1)	—	—	0.30	
R _{th(j-c)Q}		Brake IGBT part (Note-1)	—	—	0.32	
R _{th(j-c)F}		Brake FWDi upper part (Note-1)	—	—	0.53	
R _{th(c-f)}	Contact Thermal Resistance	Case to fin, (per 1 module) Thermal grease applied (Note-1)	—	—	0.023	

* If you use this value, R_{th(f-a)} should be measured just under the chips.(Note-1) T_c (under the chip) measurement point is below.

(unit : mm)

axis \ arm	UP		VP		WP		UN		VN		WN		BR	
	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	Di
X	24.5	24.5	58.0	58.0	88.0	88.0	39.0	39.0	72.5	72.5	102.5	102.5	12.2	6.8
Y	57.4	46.6	57.4	46.6	57.4	46.6	28.2	38.8	28.2	38.8	28.2	38.8	27.0	61.4



Bottom view

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise noted)**INVERTER PART**

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _D = 15V, I _C = 200A V _{CIN} = 0V, Pulsed (Fig. 1)	—	1.75	2.35	V
		T _j = 25°C		—	—	
		T _j = 125°C	—	1.75	2.35	
V _{EC}	FWDi Forward Voltage	-I _C = 200A, V _D = 15V, V _{CIN} = 15V (Fig. 2)	—	1.7	2.8	V
t _{on}	Switching Time	V _D = 15V, V _{CIN} = 0V↔15V V _{CC} = 300V, I _C = 200A T _j = 125°C Inductive Load (Fig. 3,4)	0.3	0.8	2.0	μs
t _{rr}			—	0.4	0.8	
t _{c(on)}			—	0.4	1.0	
t _{off}			—	1.0	2.3	
t _{c(off)}			—	0.3	1.0	
I _{CES}	Collector-Emitter Cutoff Current	V _{CE} = V _{CES} , V _D = 15V (Fig. 5)	—	—	1	mA
		T _j = 25°C			10	
		T _j = 125°C	—	—	10	

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FLAT-BASE TYPE
INSULATED PACKAGE

BRAKE PART

Symbol	Parameter	Condition		Limits			Unit
				Min.	Typ.	Max.	
VCE(sat)	Collector-Emitter Saturation Voltage	VD = 15V, IC = 100A VCIN = 0V, Pulsed (Fig. 1)	Tj = 25°C	—	1.75	2.35	V
			Tj = 125°C	—	1.75	2.35	
VEC	FWDi Forward Voltage	-IC = 100A, VCIN = 15V, VD = 15V (Fig. 2)		—	1.7	2.8	V
ICES	Collector-Emitter Cutoff Current	VCE = VCES, VD = 15V (Fig. 5)	Tj = 25°C	—	—	1	mA
			Tj = 125°C	—	—	10	

CONTROL PART

Symbol	Parameter	Condition		Limits			Unit
				Min.	Typ.	Max.	
ID	Circuit Current	VD = 15V, V _{CIN} = 15V	V _{N1-VNC}	—	8	16	mA
			V _{P1-VPC}	—	2	4	
V _{th(ON)}	Input ON Threshold Voltage	Applied between : UP-VUPC, VP-VVPC, WP-VWPC UN • VN • WN • Br-VNC		1.2	1.5	1.8	V
V _{th(OFF)}	Input OFF Threshold Voltage			1.7	2.0	2.3	
SC	Short Circuit Trip Level	−20 ≤ T _J ≤ 125°C, VD = 15V (Fig. 3,6)	Inverter part	400	—	—	A
			Brake part	200	—	—	
t _{off(SC)}	Short Circuit Current Delay Time	VD = 15V (Fig. 3,6)	—	0.2	—	μs	
OT	Over Temperature Protection	Detect Temperature of IGBT chip	Trip level	135	—	—	°C
OT _(hys)			Hysteresis	—	20	—	
UV	Supply Circuit Under-Voltage Protection	−20 ≤ T _J ≤ 125°C	Trip level	11.5	12.0	12.5	V
UV _r			Reset level	—	12.5	—	
I _{FO(H)}	Fault Output Current	VD = 15V, V _{CIN} = 15V (Note-2)	—	—	0.01	mA	
I _{FO(L)}			—	10	15		
t _{FO}	Minimum Fault Output Pulse Width	VD = 15V (Note-2)	1.0	1.8	—	ms	

(Note-2) Fault output is given only when the internal SC, OT & UV protections schemes of either upper or lower arm device operate to protect it.

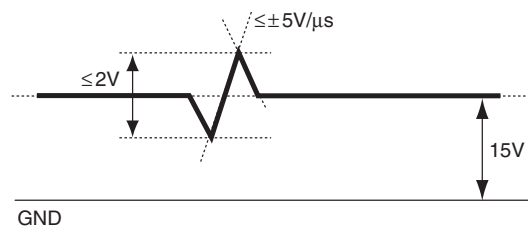
MECHANICAL RATINGS AND CHARACTERISTICS

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
—	Mounting torque	Mounting part screw : M5	2.5	3.0	3.5	$N \cdot m$
—	Mounting torque	Main terminal part screw : M5	2.5	3.0	3.5	$N \cdot m$
—	Weight	—	—	800	—	g

RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Condition	Recommended value	Unit
V_{CC}	Supply Voltage	Applied across P-N terminals	≤ 400	V
V_D	Control Supply Voltage	Applied between : $VUP1-VUPC$, $VVP1-VVPC$ $VWP1-VWPC$, $VN1-VNC$ (Note-3)	15.0 ± 1.5	V
$V_{CIN(ON)}$	Input ON Voltage	Applied between : $UP-VUPC$, $VP-VVPC$, $WP-VWPC$ $UN \cdot VN \cdot WN \cdot Br-VNC$	≤ 0.8	V
$V_{CIN(OFF)}$	Input OFF Voltage		≥ 9.0	
f_{PWM}	PWM Input Frequency	Using Application Circuit of Fig. 8	≤ 20	kHz
t_{dead}	Arm Shoot-through Blocking Time	For IPM's each input signals (Fig. 7)	≥ 2.0	μs

(Note-3) With ripple satisfying the following conditions: dv/dt swing $\leq \pm 5V/\mu s$, Variation $\leq 2V$ peak to peak



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FLAT-BASE TYPE
INSULATED PACKAGE

PRECAUTIONS FOR TESTING

- Before applying any control supply voltage (V_D), the input terminals should be pulled up by resistors, etc. to their corresponding supply voltage and each input signal should be kept off state.
After this, the specified ON and OFF level setting for each input signal should be done.
- When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above V_{CES} rating of the device.
(These test should not be done by using a curve tracer or its equivalent.)

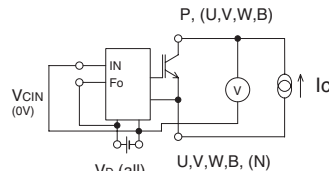


Fig. 1 $V_{CE(sat)}$ Test

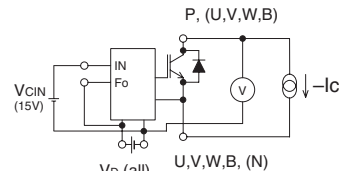


Fig. 2 V_{EC} , (V_{FM}) Test

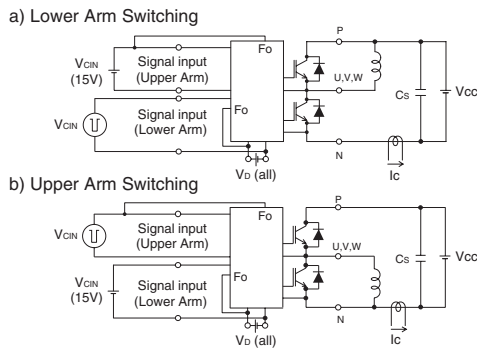


Fig. 3 Switching time and SC test circuit

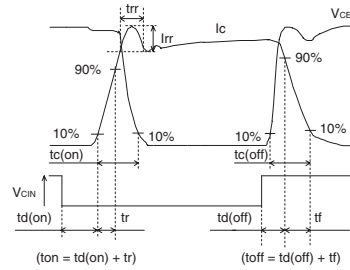


Fig. 4 Switching time test waveform

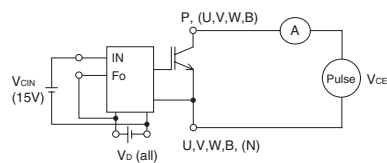


Fig. 5 I_{CES} Test

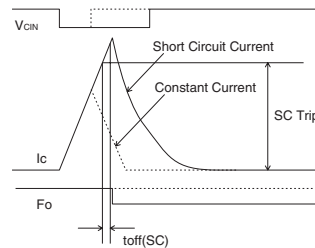
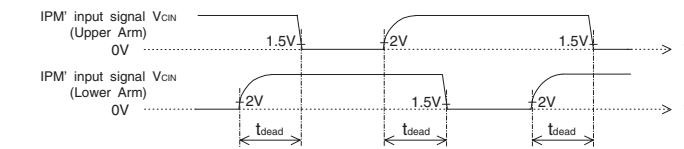


Fig. 6 SC test waveform



1.5V: Input on threshold voltage $V_{th(on)}$ typical value, 2V: Input off threshold voltage $V_{th(off)}$ typical value

Fig. 7 Dead time measurement point example

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INSULATED PACKAGE

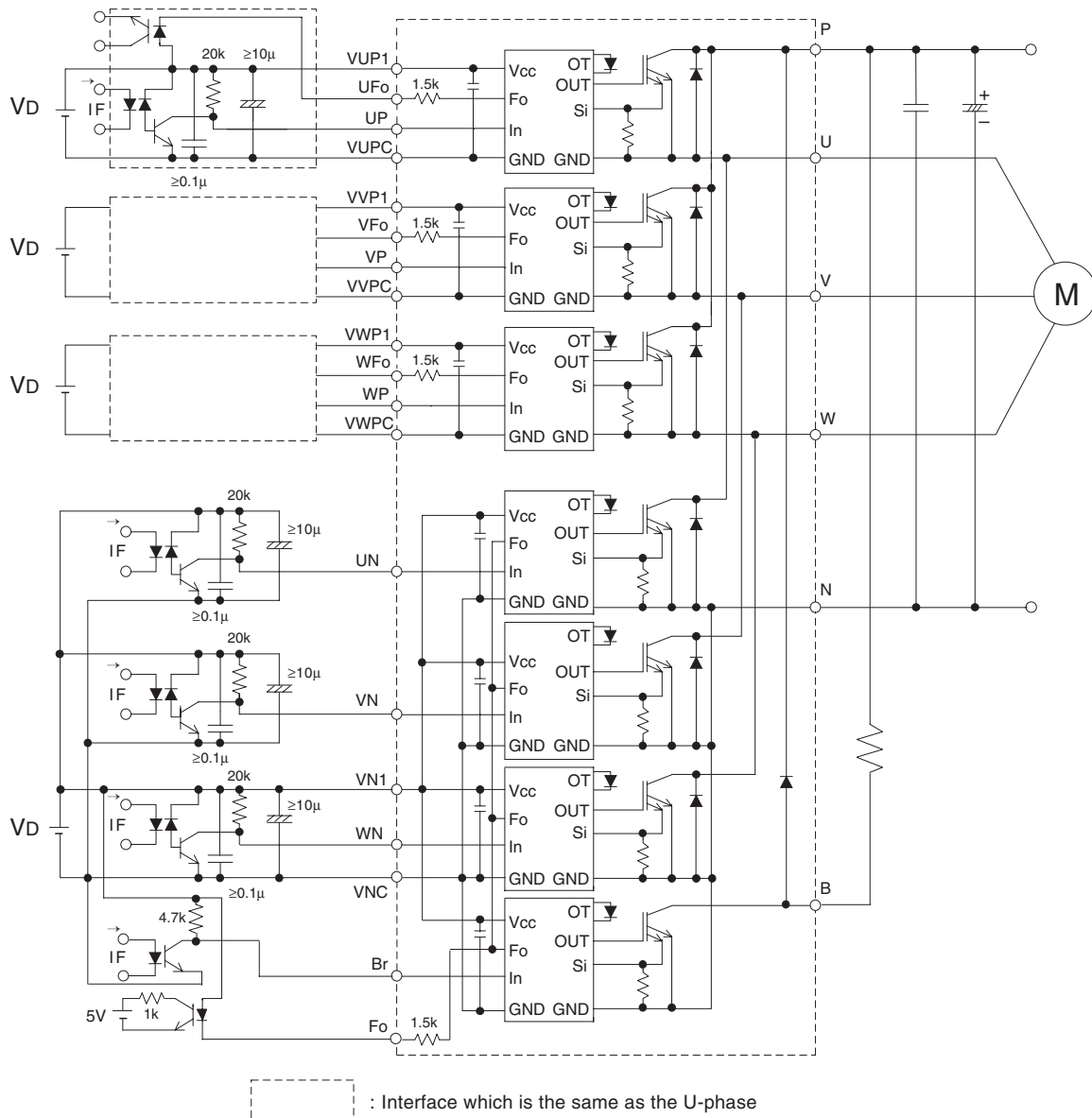


Fig. 8 Application Example Circuit

NOTES FOR STABLE AND SAFE OPERATION ;

- Design the PCB pattern to minimize wiring length between opto-coupler and IPM's input terminal, and also to minimize the stray capacity between the input and output wirings of opto-coupler.
- Connect low impedance capacitor between the Vcc and GND terminal of each fast switching opto-coupler.
- Fast switching opto-couplers: t_{PLH} , $t_{PHL} \leq 0.8\mu s$, Use High CMR type.
- Slow switching opto-coupler: CTR > 100%
- Use 4 isolated control power supplies (VD). Also, care should be taken to minimize the instantaneous voltage charge of the power supply.
- Make inductance of DC bus line as small as possible, and minimize surge voltage using snubber capacitor between P and N terminal.
- Use line noise filter capacitor (ex. 4.7nF) between each input AC line and ground to reject common-mode noise from AC line and improve noise immunity of the system.

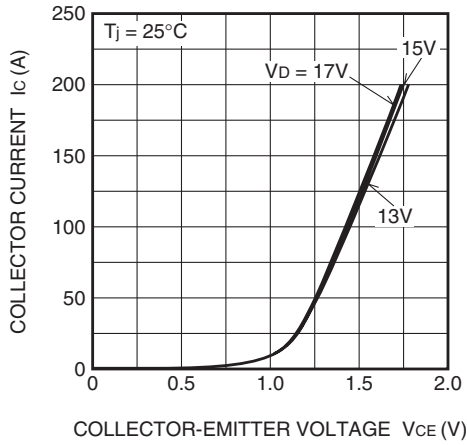
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INSULATED PACKAGE

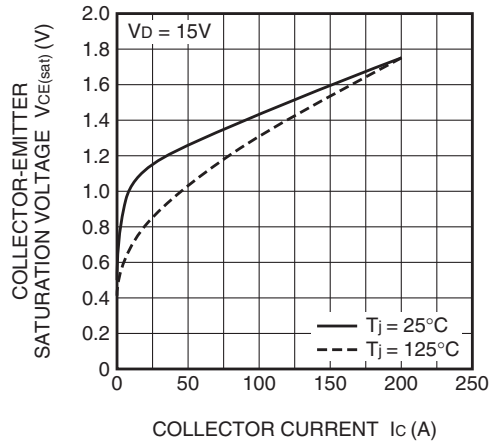
PERFORMANCE CURVES

(Inverter Part)

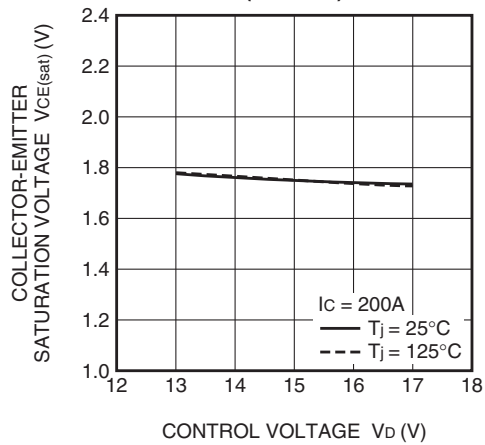
OUTPUT CHARACTERISTICS
(TYPICAL)



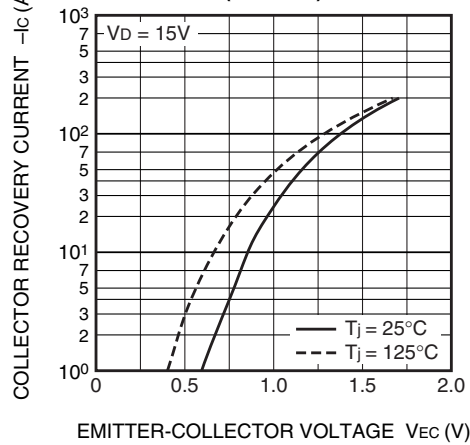
COLLECTOR-EMITTER SATURATION
VOLTAGE (VS. I_c) CHARACTERISTICS
(TYPICAL)



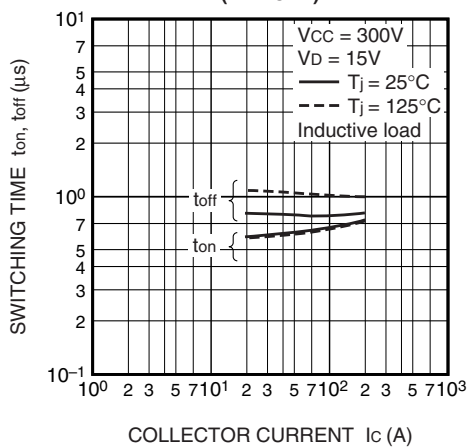
COLLECTOR-EMITTER SATURATION
VOLTAGE (VS. V_d) CHARACTERISTICS
(TYPICAL)



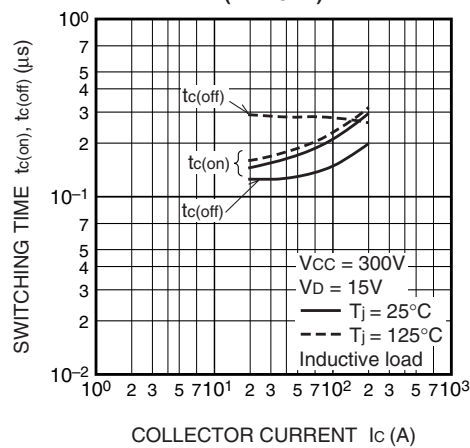
DIODE FORWARD CHARACTERISTICS
(TYPICAL)



SWITCHING TIME (t_{on} , t_{off}) CHARACTERISTICS
(TYPICAL)



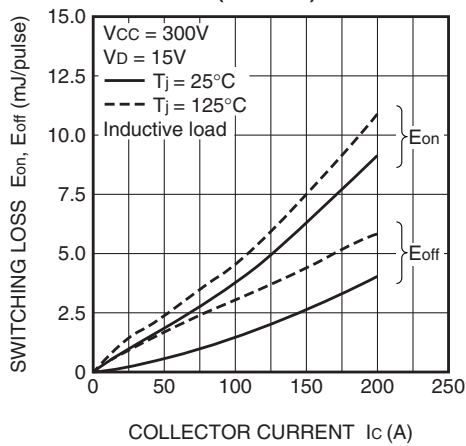
SWITCHING TIME ($t_{c(on)}$, $t_{c(off)}$) CHARACTERISTICS
(TYPICAL)



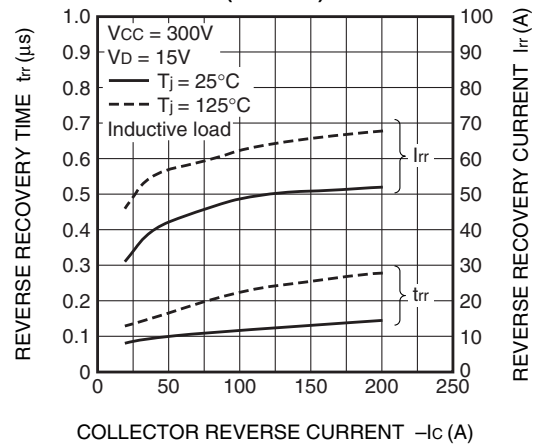
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INSULATED PACKAGE

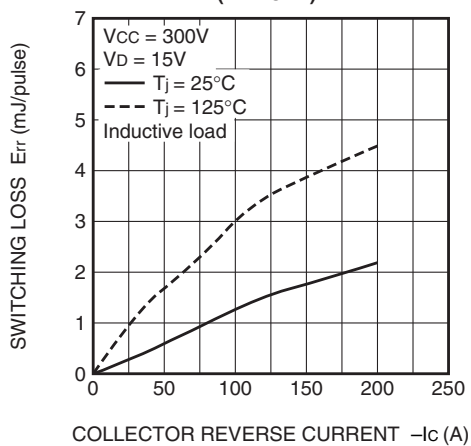
SWITCHING LOSS CHARACTERISTICS
(TYPICAL)



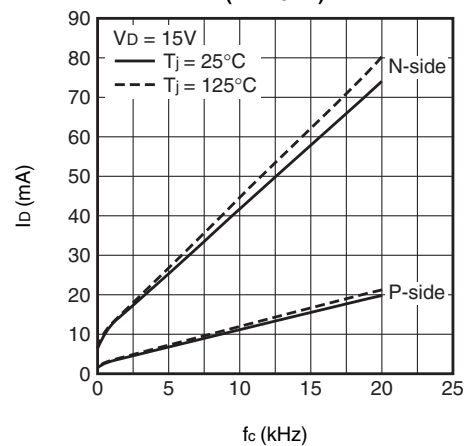
DIODE REVERSE RECOVERY CHARACTERISTICS
(TYPICAL)



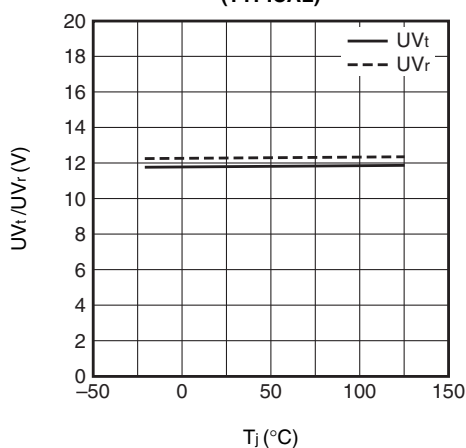
SWITCHING RECOVERY LOSS CHARACTERISTICS
(TYPICAL)



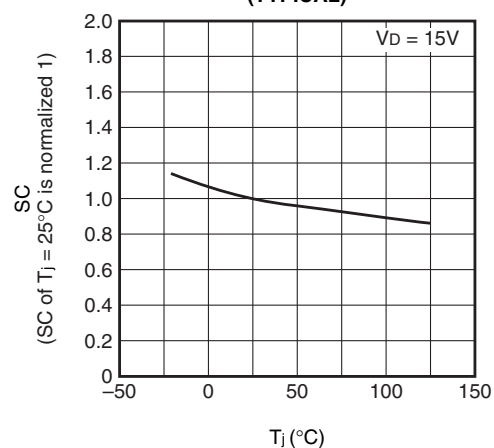
I_D VS. f_c CHARACTERISTICS
(TYPICAL)



UV TRIP LEVEL VS. T_j CHARACTERISTICS
(TYPICAL)



SC TRIP LEVEL VS. T_j CHARACTERISTICS
(TYPICAL)



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FLAT-BASE TYPE
INSULATED PACKAGE

(Brake Part)

